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Glass	
Overall Length:	
0.357 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
0.235 inches	
Joint Electronic Dev	ice Engineering Council/jedec/case Outline Designation:
Do-13	
Electrode Internally	electrically Connected To Case:
Cathode	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed of	ase
Semiconductor Mat	erial:
Silicon	
Voltage Rating In Vo	Its Per Characteristic:
20.0 regulator volta	e
Current Rating Per	Characteristic:
1.00 amperes source	cutoff current horsepower metric
Power Rating Per C	naracteristic:
1.0 watts small-signa	input power, common-collector major
Maximum Operating	Tempurature Per Measurement Point:
175.0 degrees celsiu	ambient air
Precious Material A	nd Location:
Leads gold	
Precious Material:	
Gold	
Test Data Documen	:
81349-mil-s-19500 sp	ecification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes con	mercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and pe	rformance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And	Quantity:
2 uninsulated wire lea	d
Specification Data:	
81349-mil-s-19500/50	7 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	

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